TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

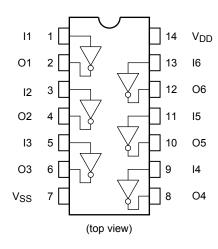
## TC4069UBP,TC4069UBF,TC4069UBFN,TC4069UBFT

#### TC4069UB Hex Inverter

TC4069UB contains six circuits of inverters. Since the internal circuit is composed of a single stage inverter, this is suitable for the applications of CR oscillator circuits, crystal oscillator circuits and linear amplifiers in addition to its application as inverters.

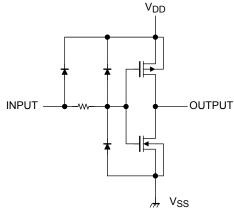
Because of one stage gate configuration, the propagation time has been reduced.

#### **Pin Assignment**



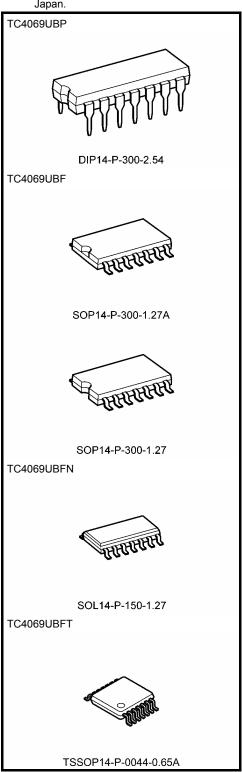
#### **Circuit Diagram**





Weight

DIP14-P-300-2.54 : 0.96 g (typ.) SOP14-P-300-1.27A : 0.18 g (typ.) SOP14-P-300-1.27 : 0.18 g (typ.) SOL14-P-150-1.27 : 0.12 g (typ.) TSSOP14-P-0044-0.65A : 0.06 g (typ.) Note: xxxFN (JEDEC SOP) is not available in Japan.





#### **Absolute Maximum Ratings (Note)**

Characteristics	Symbol	Rating	Unit
DC supply voltage	$V_{DD}$	V <sub>SS</sub> - 0.5 to V <sub>SS</sub> + 20	V
Input voltage	V <sub>IN</sub>	V <sub>SS</sub> - 0.5 to V <sub>DD</sub> + 0.5	V
Output voltage	V <sub>OUT</sub>	V <sub>SS</sub> - 0.5 to V <sub>DD</sub> + 0.5	V
DC input current	I <sub>IN</sub>	±10	mA
Power dissipation	PD	300 (DIP)/180 (SOIC)	mW
Operating temperature range	T <sub>opr</sub>	-40 to 85	°C
Storage temperature range	T <sub>stg</sub>	−65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

## Recommended Operating Conditions (V<sub>SS</sub> = 0 V) (Note)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
DC supply voltage	$V_{DD}$	_	3	_	18	V
Input voltage	V <sub>IN</sub>	_	0	_	V <sub>DD</sub>	V

Note: The recommended operating conditions are required to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.



# Static Electrical Characteristics (V<sub>SS</sub> = 0 V)

Characteristics Sy			Test Condition		-40°C			25°C			85°C	
		Symbol		V <sub>DD</sub> (V)	Min	Max	Min	Тур.	Max	Min	Max	Unit
High-leve		V <sub>ОН</sub>	$ I_{OUT}  < 1 \mu A$ $V_{IN} = V_{SS}, V_{DD}$	5 10 15	4.95 9.95 14.95	_ _ _	4.95 9.95 14.95	5.00 10.00 15.00	_ _ _	4.95 9.95 14.95	_ _ _	V
Low-leve		V <sub>OL</sub>	$ I_{OUT}  < 1 \mu A$ $V_{IN} = V_{SS}, V_{DD}$	5 10 15	_ _ _	0.05 0.05 0.05	_ _ _	0.00 0.00 0.00	0.05 0.05 0.05	_ _ _	0.05 0.05 0.05	V
Output h current	nigh	Іон	$V_{OH} = 4.6 \text{ V}$ $V_{OH} = 2.5 \text{ V}$ $V_{OH} = 9.5 \text{ V}$ $V_{OH} = 13.5 \text{ V}$ $V_{IN} = V_{SS}$	5 5 10 15	-0.61 -2.50 -1.50 -4.00		-0.51 -2.10 -1.30 -3.40	-1.0 -4.0 -2.2 -9.0	  -  -	-0.42 -1.70 -1.10 -2.80		mA
Output lo	ow	loL	$V_{OL} = 0.4 V$ $V_{OL} = 0.5 V$ $V_{OL} = 1.5 V$ $V_{IN} = V_{DD}$	5 10 15	0.61 1.50 4.00		0.51 1.30 3.40	1.2 3.2 12.0		0.42 1.10 2.80	_ _ _	mA
Input hig voltage	jh	V <sub>IH</sub>	V <sub>OUT</sub> = 0.5 V, 4.5 V V <sub>OUT</sub> = 1.0 V, 9.0 V V <sub>OUT</sub> = 1.5 V, 13.5 V  I <sub>OUT</sub>   < 1 µA	5 10 15	4.0 8.0 12.0		4.0 8.0 12.0	_ _ _		4.0 8.0 12.0	_ _ _	mA
Input low voltage	v	V <sub>IL</sub>	V <sub>OUT</sub> = 0.5 V, 4.5 V V <sub>OUT</sub> = 1.0 V, 9.0 V V <sub>OUT</sub> = 1.5 V, 13.5 V  I <sub>OUT</sub>   < 1 µA	5 10 15	  -  -	1.0 2.0 3.0	_ _ _	_ _ _	1.0 2.0 3.0	_ _ _	1.0 2.0 3.0	mA
Input current	"H" level	lін	V <sub>IL</sub> = 18 V	18		0.1		10 <sup>-5</sup>	0.1	_	1.0	
	"L" level	I <sub>IL</sub>	V <sub>IL</sub> = 0 V	18	_	-0.1	_	-10 <sup>-5</sup>	-0.1	_	-1.0	μA
Quiescei supply ci		I <sub>DD</sub>	$V_{IN} = V_{SS}, V_{DD}$ (Note)	5 10 15	_ _ _	0.25 0.50 1.00	_ _ _	0.001 0.001 0.002	0.25 0.50 1.00	_ _ _	7.5 15.0 30.0	μА

Note: All valid input combinations.

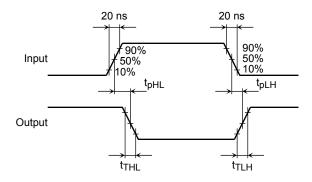


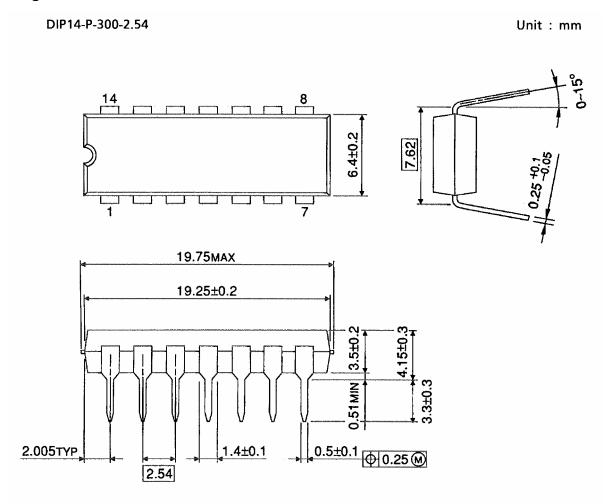
# Dynamic Electrical Characteristics (Ta = 25°C, $V_{SS}$ = 0 V, $C_L$ = 50 pF)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit	
Characteristics	Зупівої		V <sub>DD</sub> (V)	IVIII I	τyp.	IVIAX	Offic
Output transition time			5	_	70	200	
(low to high)	t <sub>TLH</sub>	_	10	_	35	100	ns
(low to riigir)			15		30	80	
Output transition time			5	_	70	200	
Output transition time (high to low)	$t_{THL}$	_	10	_	35	100	ns
(flight to low)			15	_	30	80	
Propagation delay time			5	_	55	110	
(low to high)	$t_{pLH}$	_	10	_	30	60	ns
(low to riigir)			15	_	25	50	
Propagation dolay time			5	_	55	110	
Propagation delay time (high to low)	$t_{pHL}$	_	10	_	30	60	ns
(night to low)			15	_	25	50	
Input capacitance	C <sub>IN</sub>			_	7.5	15	pF

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### **Waveform for Measurement of Dynamic Characteristics**

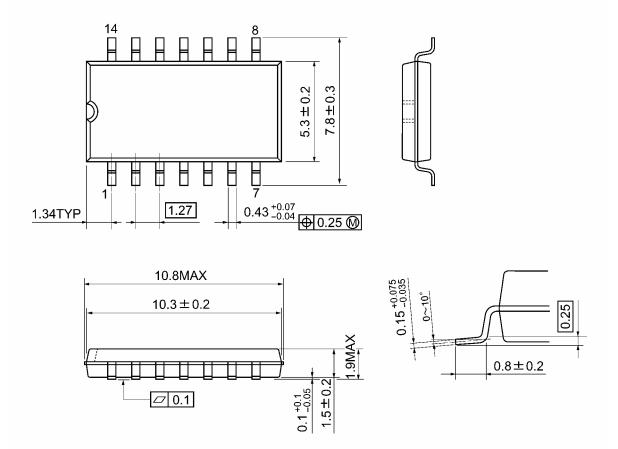




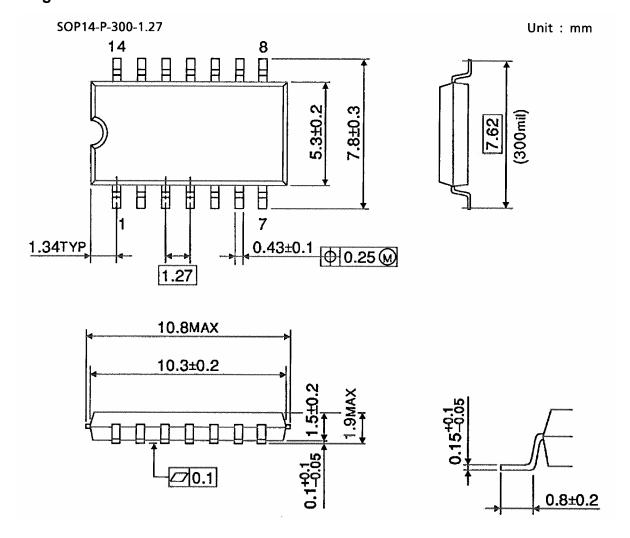
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Weight: 0.96 g (typ.)

SOP14-P-300-1.27A Unit: mm



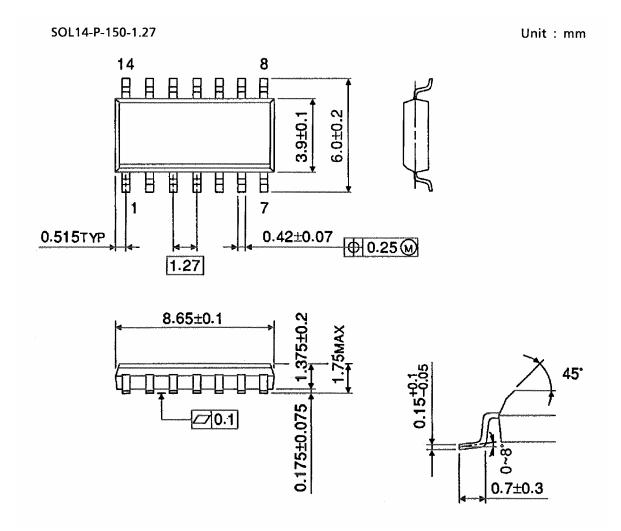
Weight: 0.18 g (typ.)



Weight: 0.18 g (typ.)



#### **Package Dimensions (Note)**

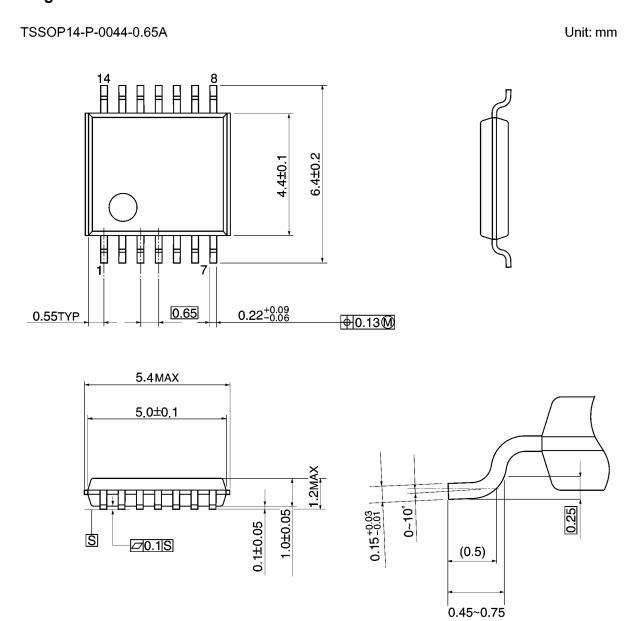


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Note: This package is not available in Japan.

Weight: 0.12 g (typ.)





Weight: 0.06 g (typ.)

Note: Lead (Pb)-Free Packages

DIP14-P-300-2.54 SOP14-P-300-1.27A SOL14-P-150-1.27 TSSOP14-P-0044-0.65A

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